NSN 5961-00-411-3012

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Unitized Semiconductor Device Rectifier - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-00-411-3012 **Overall Length:** Between 1.870 inches and 1.930 inches **Overall Height:** Between 0.721 inches and 0.841 inches Overall Width: Between 0.770 inches and 0.830 inches **Operating Tempurature Range:** -55.0/+150.0 degrees celsius **End Application:** Fighter aircraft f-14 **Circuit Connection Style Designator:** Center tap 1 phase Absolute Maximum Voltage Rating In Volts Per Characteristic: 1.5 forward voltage, peak **Absolute Maximum Current Rating Per Characteristic:** 1.00 microamperes reverse current, dc and 3.00 amperes average forward current averaged over a full 60-hz cycle and 80.00 amperes peak forward surge current **Mounting Method:** Threaded hole **Special Features:** X8ea 1n5416 forming two separate bridges; 2ea 1n5416 forming a center tap; 2ea 1n5418 forming a center tap; 2ea 1n5418 forming an inverted center tap.; additional styles are: a7 (bridge 1 phase) and a10 (inverted center tap 1 phase) Material: Silicon **Terminal Type And Quantity:** 17 turret Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: